- EPIC[™] (Enhanced-Performance Implanted CMOS) 2-µ Process
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC}, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 2 V at V_{CC}, T_A = 25°C
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JEDEC Standard JESD-17
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Ceramic (J) 300-mil DIPs

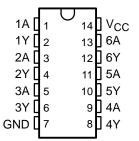
description

These hex inverters are designed for 2.7-V to $5.5\text{-V}\ \text{V}_{CC}$ operation.

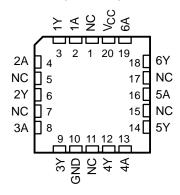
The 'LVU04 contain six independent inverters with unbuffered outputs. These devices perform the Boolean function $Y = \overline{A}$.

The SN74LVU04 is available in TI's shrink small-outline package (DB), which provides the same I/O pin count and functionality of standard small-outline packages in less than half the printed-circuit-board area.

SN54LVU04 . . . J OR W PACKAGE SN74LVU04 . . . D, DB, OR PW PACKAGE (TOP VIEW)



SN54LVU04 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

The SN54LVU04 is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74LVU04 is characterized for operation from -40° C to 85° C.

FUNCTION TABLE (each inverter)

INPUT A	OUTPUT Y
Н	L
L	Н



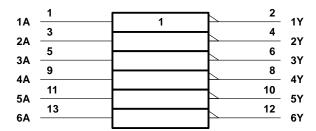
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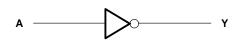
EPIC is a trademark of Texas Instruments Incorporated.



logic symbol†

logic diagram, each inverter (positive logic)





Pin numbers shown are for D, DB, J, PW and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}	$-0.5\ V$ to 7 V
Input voltage range, V _I (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Output voltage range, VO (see Notes 1 and 2)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	$\dots \dots \pm 20 \; mA$
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	$\dots \dots \pm 50 \text{ mA}$
Continuous output current, I_O ($V_O = 0$ to V_{CC})	$\dots \dots \pm 25 \text{ mA}$
Continuous current through V _{CC} or GND	$\dots \dots \pm 50 \text{ mA}$
Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 3): D package	1.25 W
DB or PW package	0.5 W
Storage temperature range, T _{stq}	65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stressratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. This value is limited to 7 V maximum.
 - 3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils.

recommended operating conditions (see Note 4)

			SN54L	SN54LVU04		4LVU04 SN74LVU04		UNIT
			MIN	MAX	MIN	MAX	UNIT	
VCC	Supply voltage		2.7	5.5	2.7	5.5	V	
V	High level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.4		2.4		V	
VIH	High-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	3.55		3.55		V	
V	Low lovel input voltage	V _{CC} = 2.7 V to 3.6 V		0.5		0.5	V	
VIL	Low-level input voltage $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.8		0.8	V		
٧ı	Input voltage		0.4	Vcc	0	Vcc	V	
٧o	Output voltage		0	VCC	0	VCC	V	
1	High lovel output ourrent	V _{CC} = 2.7 V to 3.6 V	2	-6		-6	A	
ЮН	High-level output current	V _{CC} = 4.5 V to 5.5 V	Q.	-12		-12	mA	
	I am laval autout arment	V _{CC} = 2.7 V to 3.6 V		6		6	A	
IOL	Low-level output current $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$			12		12	mA	
Δt/Δν	Input transition rise or fall rate		0	100	0	100	ns/V	
TA	Operating free-air temperature		-55	125	-40	85	°C	

NOTE 4: Unused inputs must be held high or low to prevent them from floating.



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		v _{cc} †	SN	54LVU0	4	SN)4	UNIT	
PARAMETER	TEST COI	1231 CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	UNIT
	$V_I = V_{IL}$	$I_{OH} = -100 \mu A$	MIN to MAX	V _{CC} -0.	5		V _{CC} -0.	5		
Voн	$V_I = GND$,	$I_{OH} = -6 \text{ mA}$	3 V	2.4			2.4			V
	$V_I = GND,$	$I_{OH} = -12 \text{ mA}$	4.5 V	3.6			3.6			
	$V_I = V_{IH}$, $I_{OL} = 100 \mu A$		MIN to MAX			0.5			0.5	
VOL	$V_I = V_{CC}$	$I_{OL} = 6 \text{ mA}$	3 V		14	0.4			0.4	V
	$V_I = V_{CC}$	$I_{OL} = 12 \text{ mA}$	4.5 V		KI	0.55			0.55	
1.	VI = VOO OF GND		3.6 V		2	±1			±1	
ΙΙ	V _I = V _{CC} or GND		5.5 V		Ć,	±1			±1	μΑ
laa	VI – Voo or CND	I _O = 0	3.6 V	100		20			20	
lcc	$V_I = V_{CC}$ or GND,	1O = 0	5.5 V	Q'		20			20	μΑ
ΔICC	One input at V _{CC} – 0 Other inputs at V _{CC}		3 V to 3.6 V			500			500	μΑ
C.	VI = VOC or GND		3.3 V		7			7		pF
C _i	$V_I = V_{CC}$ or GND	5 V		7.5			7.5		þΓ	

[†] For conditions shown as MIN or MAX, use the appropriate values under recommended operating conditions.

switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

			SN54LVU04							
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5 V \pm 0.5 V$		$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$ $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 2.3 \text{ V} \pm 0.3 \text{ V}$			2.7 V	UNIT	
	(01)	(001101)	MIN	TYP MAX	MIN	TYP	MAX	MIN	MAX	
^t pd	Α	Υ		5 10		8	13	P.F.	13	ns

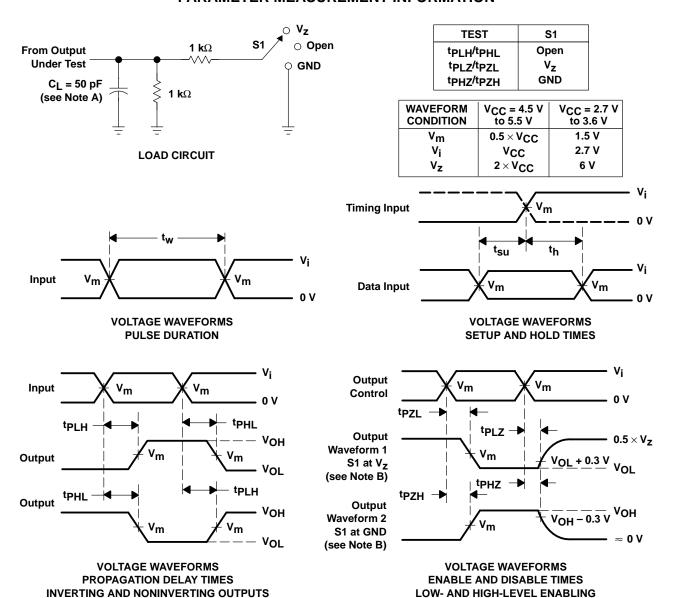
switching characteristics over recommended operating free-air temperature range, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER						SN74L	.VU04				
	FROM (INPUT)	TO (OUTPUT)	VCC :	$V_{CC} = 5 V \pm 0.5 V$		V _{CC} = 5 V ± 0.5 V V _{CC} = 3		3.3 V ±	0.3 V	VCC =	2.7 V
		(0011 01)	MIN	TYP	MAX	MIN	TYP	MAX	MIN	MAX	
t _{pd}	A	Y		5	10		8	13		13	ns

operating characteristics, $T_A = 25^{\circ}C$

PARAMETER		TEST COI	VCC	TYP	UNIT	
Cod	Power dissipation capacitance per inverter	Cu = 50 pF	f = 10 MHz	3.3 V	7	ρF
Cpd	i ower dissipation capacitance per inverter	on capacitance per inverter $C_L = 50 \text{ pF}, f = 100 \text{ pF}$	_L = 50 pr,	5 V	12	рі

PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \ \Omega$, $t_f \leq 2.5 \ ns$, $t_f \leq 2.5 \ ns$.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tplH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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